



High-Current Switching Applications

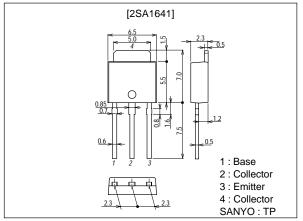
Features

- · Adoption of FBET, MBIT processes.
- · Low saturation voltage.
- · Fast switching speed.
- · Large current capacity.
- · Small and slim package making it easy to make 2SA1641-used set smaller.

Package Dimensions

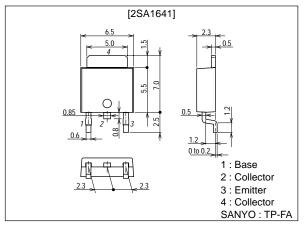
unit:mm

2045B



unit:mm

2044B



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Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		-25	V
Collector-to-Emitter Voltage	V _{CEO}		-20	V
Emitter-to-Base Voltage	V _{EBO}		-5	V
Collector Current	IС		-8	Α
Colletor Current (Pulse)	I _{CP}		-12	Α
Base Current	I _B		-1.5	Α
Collector Dissipation	D-		1	W
	PC	Tc=25°C	15	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

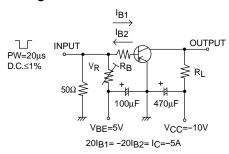
Electrical Characteristics at Ta = 25°C

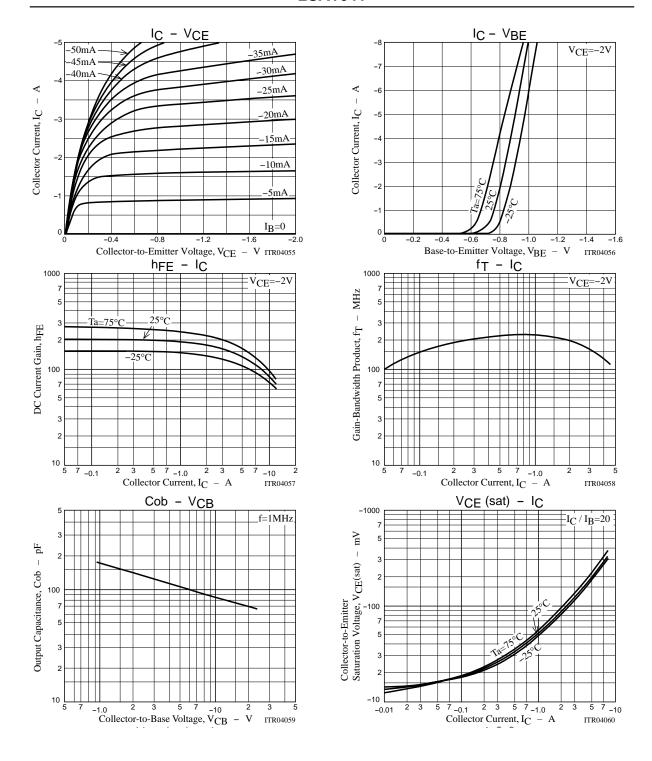
Parameter	Symbol	Conditions	Ratings			Unit
Parameter		Conditions		typ	max	Uill
Collector Cutoff Current	ICBO	V _{CB} =-20V, I _E =0			-1	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =-4V, I _C =0			-1	μΑ
DC Current Gain	h _{FE} 1	V _{CE} =-2V, I _C =-500mA			400*	
DC Current Gain	h _{FE} 2	V _{CE} =-2V, I _C =-6A				
Gain-Bandwidth Product	f _T	V _{CE} =-2V, I _C =-500mA		200		MHz
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =-5A, I _B =-250mA		-220	-400	mV
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =-5A, I _B =-250mA		-1	-1.3	V
Collector Output Capacitance	C _{ob}	V _{CB} =-10V, f=1MHz		85		pF
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =-10μA, I _E =0				V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =-1mA, R _{BE} =∞	-20			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =-10μA, I _C =0				V
Turn-ON Time	t _{on}	See specified Test Circuit		30	300	ns
Storage Time	t _{stg}	See specified Test Circuit		200	800	ns
Fall Time	t _f	See specified Test Circuit		15	150	ns

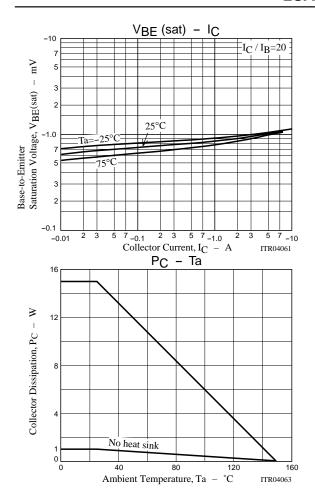
 $[\]ast$: The 2SA1641 is classified by 500mA h_{FE} as follows :

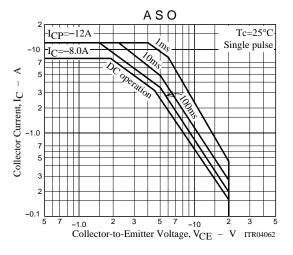
Rank	R	S	Т	
hFE	100 to 200	140 to 280	200 to 400	

Switching Time Test Circuit









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